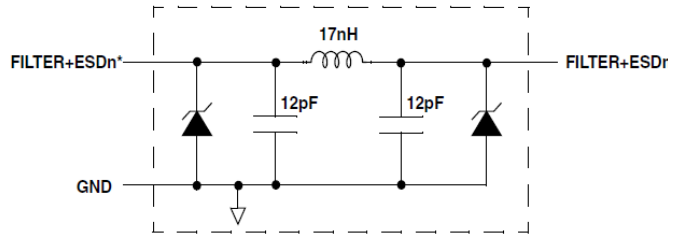
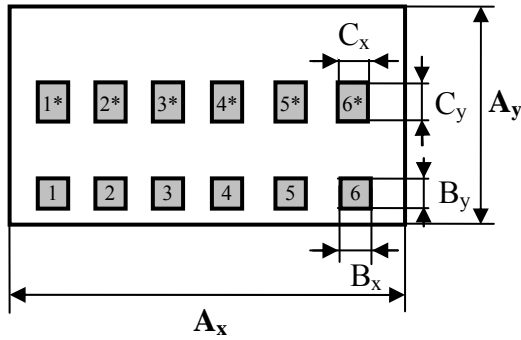




LC-306  
PRELIMINARY

6 Channel L-C EMI Filter Array with ESD Protection.



**Mechanical date:**  $A_x=1940\mu\text{m}$ ,  $A_y=480\mu\text{m}$ .  
 $B_x=70\mu\text{m}$ ,  $B_y=70\mu\text{m}$   
 $C_x=82\mu\text{m}$ ,  $C_y=96\mu\text{m}$

Schematic and pinning diagram.

**Chip thickness:**  $138\pm 12\mu\text{m}$ .  
**Scribe Line width** -  $60\mu\text{m}$ .  
**Top Metal:** Al – for wire bonding,  $d=2.2\pm 0.2\mu\text{m}$ .  
**Back side:** Ti-Ni-Ag for soldering.  
**Back side – GND**

Limiting values

Parameter	Symbol	Conditions	Value	Unit
Electrostatic Discharge	$V_{ESD}$	IEC 61000-4-2, level 4	$\pm 15$ (Contact)	kV
Max. junction temperature	$T_j$	—	125	$^{\circ}\text{C}$

Characteristics ( $T_j=25^{\circ}\text{C}$ )

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
L	Channel Inductance	—	—	17	—	nH
$C_{TOTAL}$	Total Channel Capacitance	$V_R=2.5\text{V}$ , 1MHz	18.8	23.5	28.2	pF
$I_R$	Diode reverse leakage current	$V=+3.3\text{V}$	—	0.1	1.0	$\mu\text{A}$
$V_{SIG}$	Signal Clamp Voltage Positive Clamp	$I_{LOAD}=10\text{ mA}$	5.6	6.8	9	V
	Negative Clamp	$I_{LOAD}= -10\text{ mA}$	-1.5	-0.8	-0.4	V